

= 2x

=

V<sub>RRM</sub>

VF

# Schottky Diode Gen<sup>2</sup>

preliminary

15 A

0.54 V

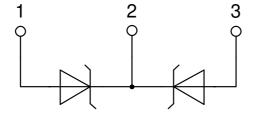
High Performance Schottky Diode Low Loss and Soft Recovery **Common Cathode** 

Part number

DSB30C45HB



Backside: cathode



#### Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation • Low voltage peaks for reduced
- Low noise switching
- protection circuits

### **Applications:**

- · Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

#### Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

#### **Disclaimer Notice**

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Schottky			Ratings				
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			45	V
V <sub>RRM</sub>	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			45	V
I <sub>R</sub>	reverse current, drain current	$V_{R} = 45 V$	$T_{VJ} = 25^{\circ}C$			5	mA
		$V_{R} = 45 V$	$T_{vJ} = 100^{\circ}C$			50	mA
VF	forward voltage drop	I <sub>F</sub> = 15 A	$T_{VJ} = 25^{\circ}C$			0.58	V
		$I_{F} = 30 \text{ A}$				0.82	V
		I <sub>F</sub> = 15 A	T <sub>vJ</sub> = 125°C			0.54	V
		$I_{F} = 30 \text{ A}$				0.78	V
	average forward current	T <sub>c</sub> = 130°C	T <sub>vJ</sub> = 150°C			15	Α
		rectangular d = 0.5					
V <sub>F0</sub>	threshold voltage		T <sub>vJ</sub> = 150°C			0.31	V
r <sub>F</sub>	slope resistance } for power lo	ess calculation only				14.9	mΩ
$\mathbf{R}_{thJC}$	thermal resistance junction to case	e				1.75	K/W
R <sub>thCH</sub>	thermal resistance case to heatsin	nk			0.3		K/W
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			70	W
FSM	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_{R} = 0 V$	$T_{vJ} = 45^{\circ}C$			340	Α
C	junction capacitance	$V_{R} = 5V f = 1 MHz$	$T_{vJ} = 25^{\circ}C$		497		pF

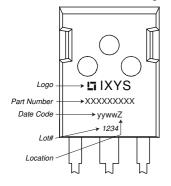
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Package TO-247				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I <sub>RMS</sub>	RMS current	per terminal "			50	Α	
T <sub>vJ</sub>	virtual junction temperature		-55		150	°C	
T <sub>op</sub>	operation temperature		-55		125	°C	
T <sub>stg</sub>	storage temperature		-55		150	°C	
Weight				6		g	
M <sub>D</sub>	mounting torque		0.8		1.2	Nm	
F <sub>c</sub>	mounting force with clip		20		120	Ν	

### **Product Marking**



#### Part description

- D = Diode
- S = Schottky Diode B = ultra low VF
- 30 = Current Rating [A]
- C = Common Cathode
- 45 = Reverse Voltage [V]
- HB = TO-247AD (3)

Ordering	Ordering Number	Marking on Product	king on Product Delivery Mode		Code No.
Standard	DSB30C45HB	DSB30C45HB	Tube	30	504141

Similar Part	Package	Voltage class
DSB30C45PB	TO-220AB (3)	45

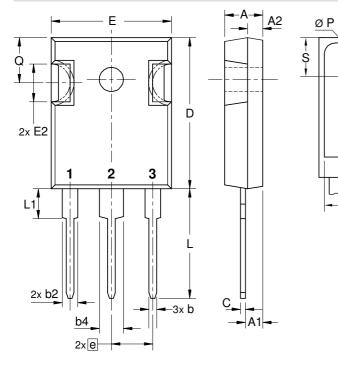
Equiva	lent Circuits for	Simulation	* on die level	$T_{VJ} = 150^{\circ}C$
	)[R	Schottky		
V <sub>0 max</sub>	threshold voltage	0.31		V
$\mathbf{R}_{0 \text{ max}}$	slope resistance *	12.4		mΩ

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Sym.	Inches		Millimeter		
	min.	max.	min.	max.	
А	0.185	0.209	4.70	5.30	
A1	0.087	0.102	2.21	2.59	
A2	0.059	0.098	1.50	2.49	
D	0.819	0.845	20.79	21.45	
E	0.610	0.640	15.48	16.24	
E2	0.170	0.216	4.31	5.48	
е	0.215	BSC	5.46 BSC		
L	0.780	0.800	19.80	20.30	
L1	-	0.177	-	4.49	
ØΡ	0.140	0.144	3.55	3.65	
Q	0.212	0.244	5.38	6.19	
S	0.242	BSC	6.14 BSC		
b	0.039	0.055	0.99	1.40	
b2	0.065	0.094	1.65	2.39	
b4	0.102	0.135	2.59	3.43	
с	0.015	0.035	0.38	0.89	
D1	0.515	-	13.07	-	
D2	0.020	0.053	0.51	1.35	
E1	0.530	-	13.45	-	
ØP1	-	0.29	-	7.39	

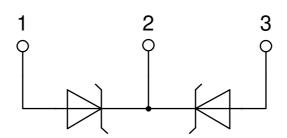
<u>D2</u>

D1

Ø P1

4

E1



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Schottky

# DSB30C45HB

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